

Preliminary Data Sheet

3.0 Amp Glass Passivated Sintered Fast Efficient Rectifiers

EGFZ30A . . . 30M Series

Description

Package "SMC" -7.75/8.12 -1.91/2.41 -0.051/.152

Features

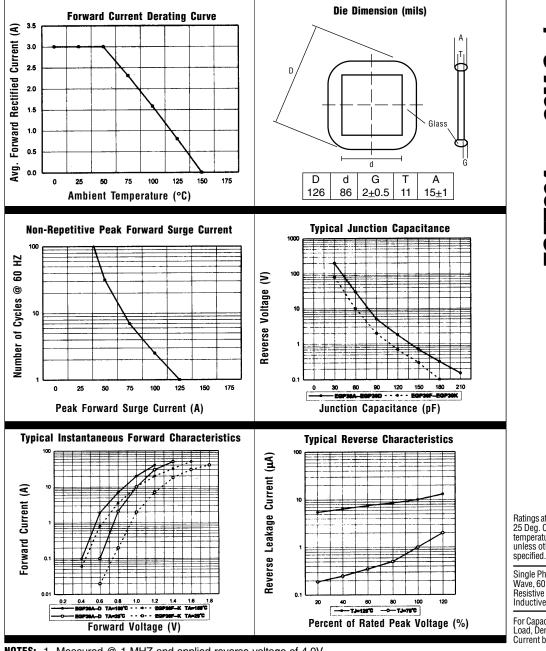
- LOWEST COST FOR GLASS SINTERED FAST EFFICIENT CONSTRUCTION
- LOWEST V_F FOR GLASS SINTERED FAST EFFICIENT CONSTRUCTION
- TYPICAL I_p < 100 nAmps

- 3.0 AMP OPERATION @ T_A = 55°C, WITH NO THERMAL RUNAWAY
- SINTERED GLASS CAVITY-FREE JUNCTION

Electrical Characteristics @ 25°C.	EGFZ30A 30M Series							Units
Maximum Ratings	30A	30B	30D	30G	30J	30K	30M	
Peak Repetitive Reverse VoltageV _{RRM}	50	100	200	400	600	800	1000	Volts
RMS Reverse VoltageV _{R(rms)}	35	70	140	280	420	560	700	Volts
DC Blocking VoltageV _{DC}	50	100	200	400	600	800	1000	Volts
Average Forward Rectified CurrentI $_{\rm F(av)}$ Current 3/8" Lead Length @ $\rm T_A = 55^{\circ}\rm C$	3.0							Amps
Non-Repetitive Peak Forward Surge CurrentI _{FSM} 8.3mS, ½ Sine Wave Superimposed on Rated Load	125							Amp
Forward Voltage @ 3.0AV _F	<	1.0 .	>	1.3	<	1.7 .	>	Volts
DC Reverse CurrentI _{R(max)} $T_A = 25^{\circ}C$ @ Rated DC Blocking Voltage $T_A = 125^{\circ}C$	5.0 100							μAm
Typical Junction CapacitanceC _J (Note 1)	60							pF
Typical Thermal ResistanceR _{eJA} (Note 2)								°C/W
Maximum Reverse Recovery Timet _{RR} (Note 3)	< 50							nS
Operating & Storage Temperature RangeT _J , T _{STRG}	65 to 150							°C



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NOTES: 1. Measured @ 1 MHZ and applied reverse voltage of 4.0V.

- 2. Thermal Resistance from Junction to Ambient at 3/8" Lead Length, P.C. Board Mounted.
- 3. Reverse Recovery Condition $\rm I_F$ = 0.5A, $\rm I_R$ = 1.0A, $\rm I_{RR}$ = 0.25A.

Ratings at 25 Deg. C ambient temperature unless otherwise

Single Phase Half Wave, 60 HZ Resistive or Inductive Load.

For Capacitive Load, Derate Current by 20%.